

Electronic Supplementary Material (ESI) for Physical Chemistry Chemical Physics.

## Supporting Information

Bioinspired hierarchical cross-linked graphene-silicon nanofilms  
via synergistic interfacial interactions as integrated negative  
electrodes for high-performance lithium storage

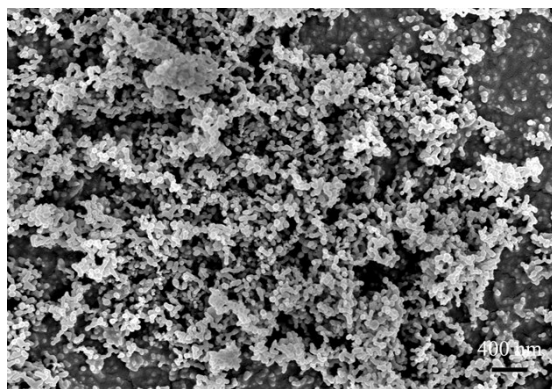
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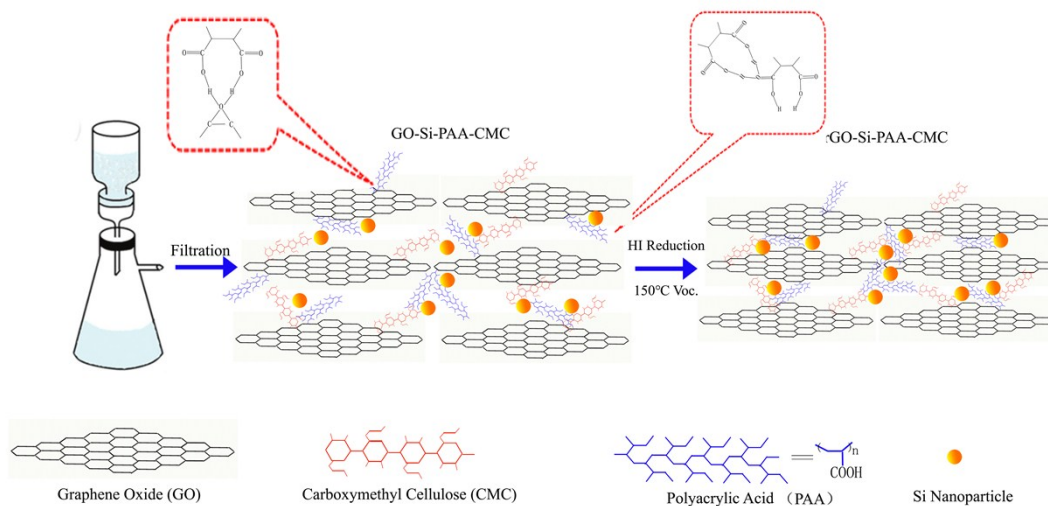
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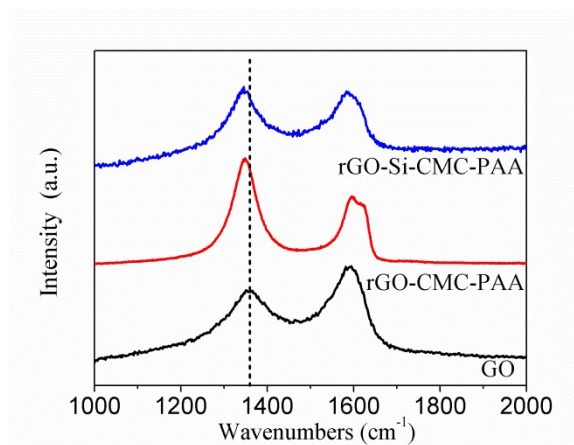
E-mail address: wangbo@buaa.edu.cn.



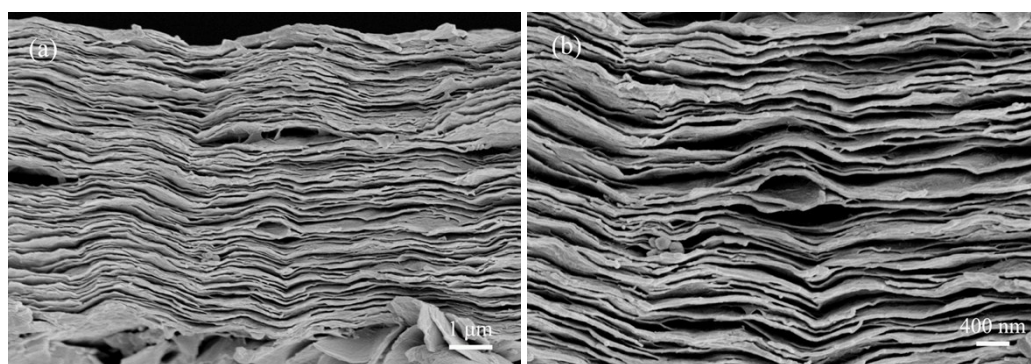
**Fig. S1** The SEM image of the Si nanoparticles powders.



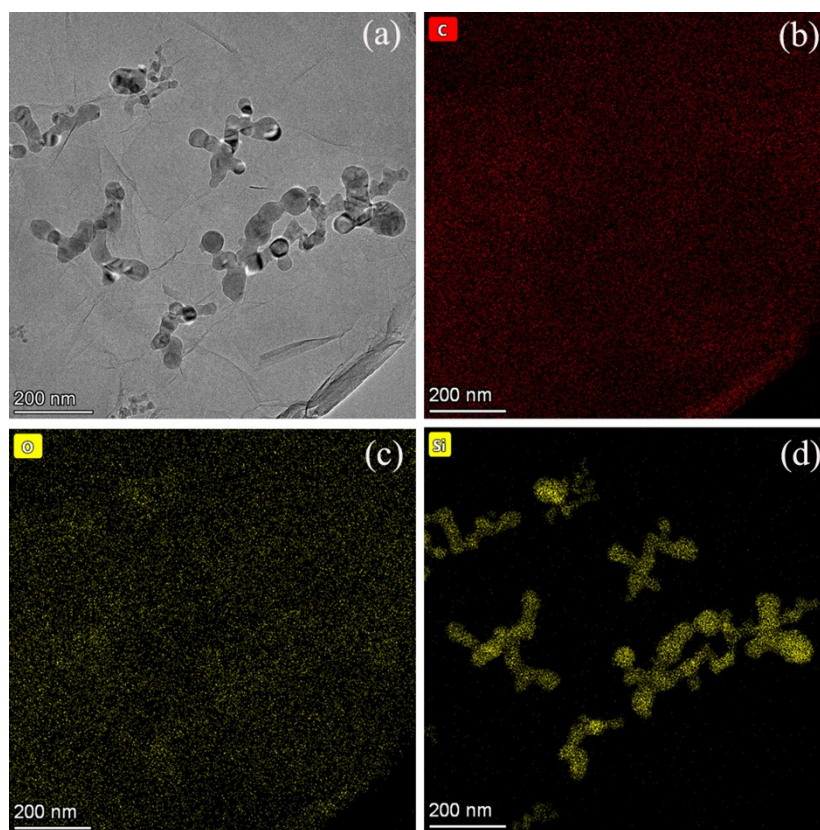
**Fig. S2** Schematic illustration of the synthesis process of rGO-Si-CMC-PAA films.



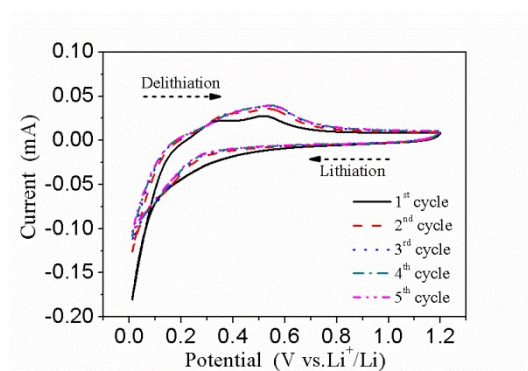
**Fig. S3** The enlargement of Raman spectra of as-prepared GO and rGO-Si-CMC-PAA films.



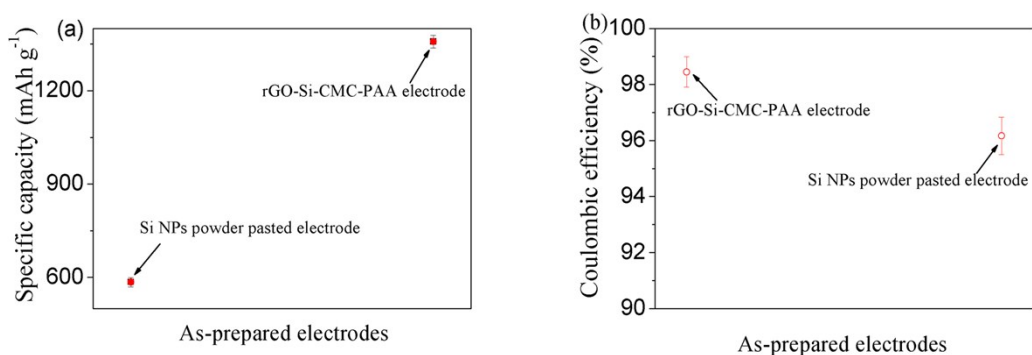
**Fig. S4** (a-b) SEM images of the as-prepared rGO-CMC-PAA nanocomposites at different magnifications.



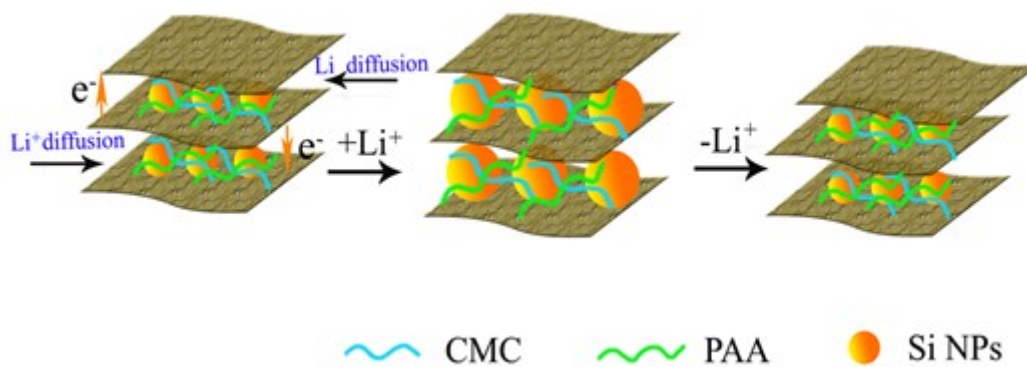
**Fig. S5** (a) TEM and (b-d) corresponding element mappings of rGO-Si-CMC-PAA films.



**Fig. S6** Cyclic voltammograms of Si NPs powder pasted electrode for the initial five cycles at a scan rate of  $0.1 \text{ mV s}^{-1}$  in the voltage range of 0.01-1.2 V.



**Fig. S7** (a) The specific capacity and (b) Coulombic efficiency of conventional Si NPs powder pasted electrode and rGO-Si-CMC-PAA electrodes at the current density of 0.1C after 800 cycles; the scatter bands in the plots are standard deviations calculated from 10 parallel electrodes.



**Fig. S8** Possible working mechanism of rGO-Si-CMC-PAA electrode to accommodate the considerable volume change of Si particles during cycling.

**Table S1** The elemental composition of the rGO-Si-CMC-PAA films from the EDS  
(Fig. 3h) .

<i>Elem</i>	<i>Weight %</i>	<i>Atomic %</i>
<i>C K</i>	45.86	49.69
<i>O K</i>	11.05	14.19
<i>Si K</i>	43.09	36.12